

transphorm  Image may be representation. See specs for product details.	TPH3208PD
	Manufacturer Part Number: TPH3208PD Manufacturer/Brand: Transphorm Part of Description: MOSFET N-CH 650V 20A TO220 Datasheets:  TPH3208PD.pdf RoHs Status:  Lead free / RoHS Stock Condition: Compliant New original, 2593 pcs Stock Available. Ship From: Hong Kong Shipment Way: DHL/Fedex/TNT/UPS/EMS

Specifications	
Part Number	TPH3208PD
Manufacturer	Transphorm
Description	MOSFET N-CH 650V 20A TO220
Category	Discrete Semiconductor Products > Transistors - FETs,
Part Status	2593 pcs Stock
Technology	GaNFET (Gallium Nitride)
Supplier Device Package	TO-220
Series	-
Packaging	Tube
Package / Case	TO-220-3
Operating Temperature	-55°C ~ 150°C
Mounting Type	Through Hole
Moisture Sensitivity Level (MSL)	1 (Unlimited)
Lead Free Status / RoHS Status	Lead free / RoHS Compliant
Input Capacitance (Ciss) (Max) @ Vds	760pF @ 400V
Gate Charge (Qg) (Max) @ Vgs	14nC @ 8V
FET Type	N-Channel
FET Feature	-
Drain to Source Voltage (Vdss)	650V
Detailed Description	N-Channel 650V 20A (Tc) Through Hole TO-220
Current - Continuous Drain (Id) @ 25°C	20A (Tc)

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